

/ Descriptions

WR0553 M M E QSQ Æ M ç s ll 1 Silicon NPN transistor in a TO-220 Plastic Package.

/ Features

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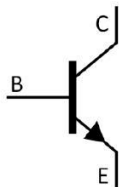
low collector saturation voltage, fast switching speed, wide base reverse-bias SOA.

/ Applications

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High-speed high-voltage converters, and high-frequency power amplifiers.

/ Equivalent Circuit



/ Pinning



1 2 3

PIN1 χ Base

PIN 2 χ Collector

PIN 3 χ Emitter

/ h_{FE} Classifications & Marking

ð M 1 ç " See Marking Instructions.

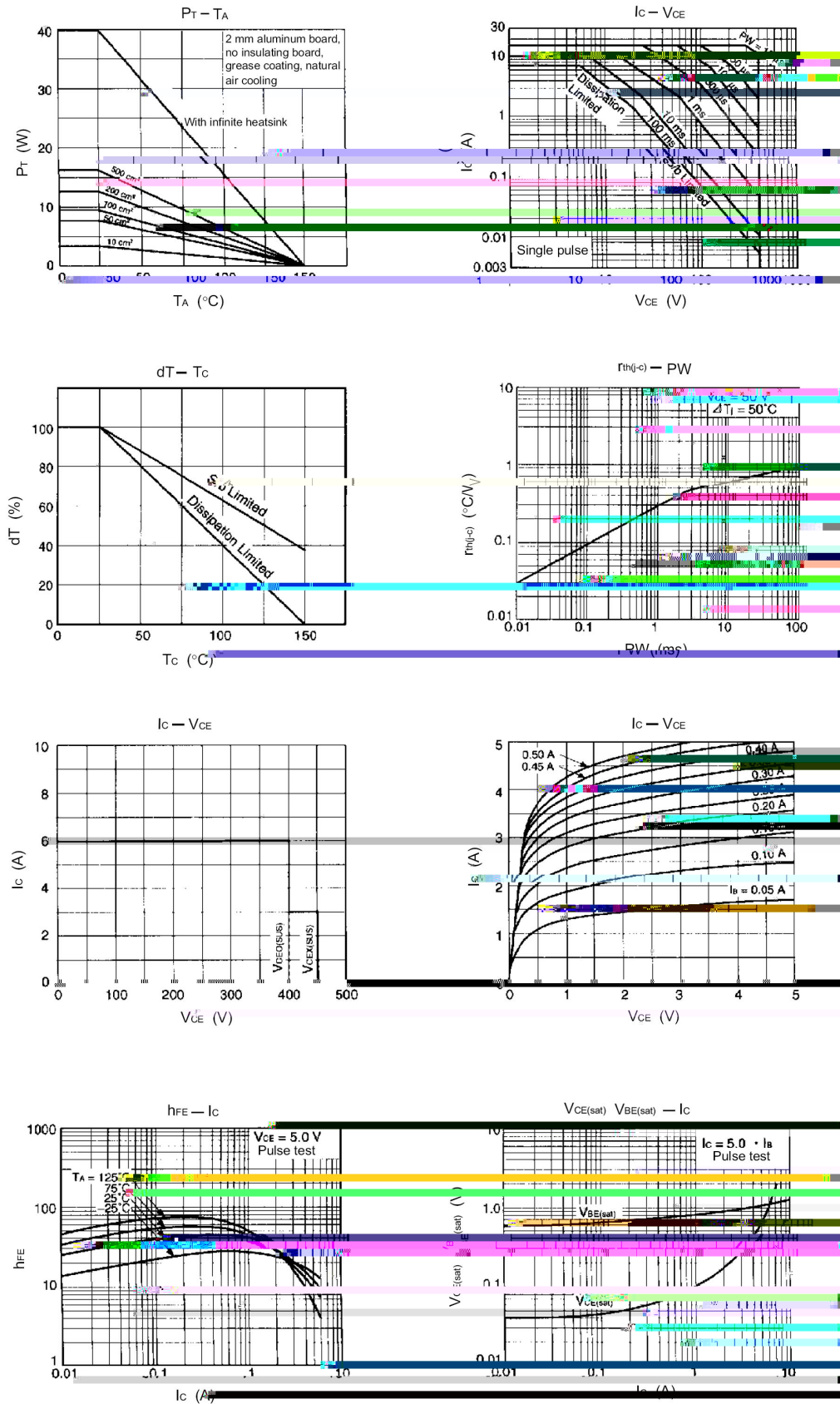
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	500	V
Collector to Emitter Voltage	V_{CEO}	400	V
Emitter to Base Voltage	V_{EBO}	7.0	V
Collector Current - Continuous	I_C	7.0	A
Base Current - Continuous	I_B	3.5	A
Collector Power Dissipation	P_C	1.5	W
	$P_C(T_c=25)$	40	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 ~ 150	

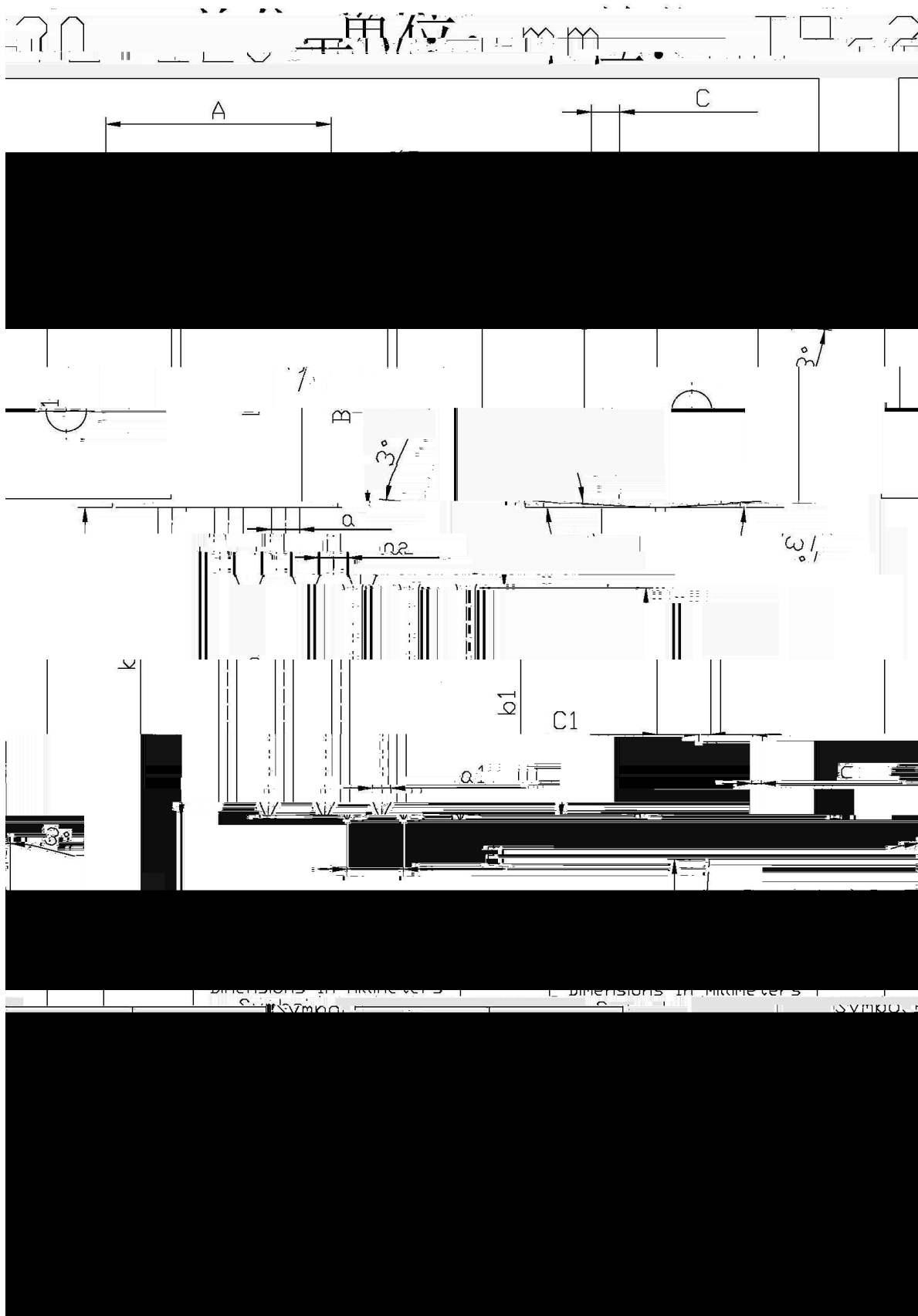
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C=3A$ $I_{B1}=0.6A$ $L=1mH$	400			V
Collector to Emitter Breakdown Voltage	$V_{CEX(SUS)1}$	$I_C=3A$ $I_{B1}=-I_{B2}=0.6A$ $V_{BE(OFF)}=-5V$ $L=180H$	450			V
	$V_{CEX(SUS)2}$	$I_C=6A$ $I_{B1}=2A$ $-I_{B2}=0.6A$ $V_{BE(OFF)}=-5V$ $L=180H$	400			V
Collector Cut-Off Current	I_{CBO}	$V_{CB}=400V$ $I_E=0$			1.0	A
Collector Cut-Off Current	I_{CER}	$V_{CE}=400V$ $R_{BE}=51$ $T_A=125$			1.0	mA
Collector Cut-Off Current	I_{CEX1}	$V_{CE}=400V$ $R_{BE(OFF)}=-1.5V$			10	A
	I_{CEX2}	$V_{CE}=400V$ $R_{BE}=-1.5V$ $T_A=125$			1.0	mA
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=5V$ $I_C=0$			10	A
DC Current Gain	$h_{FE(1)}$	$V_{CE}=5V$ $I_C=0.1A$	20		80	
	$h_{FE(2)}$	$V_{CE}=5V$ $I_C=1A$	20		80	
	$h_{FE(3)}$	$V_{CE}=5V$ $I_C=3A$	10			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=3A$ $I_B=0.6A$			1.0	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=3A$ $I_B=0.6A$			1.2	V
Turn-On Time	t_{on}	$I_C=3A$ $R_L=50$ $I_{B1}=-I_{B2}=0.6A$ $V_{CC}=150V$			1.0	S
Storage Time	t_{stg}	Refer to the test circuit			2.5	S
Fall Time	t_r				1.0	S

/ Electrical Characteristic Curve



/ Package Dimensions



Lot No. Code, code change with Lot No.

